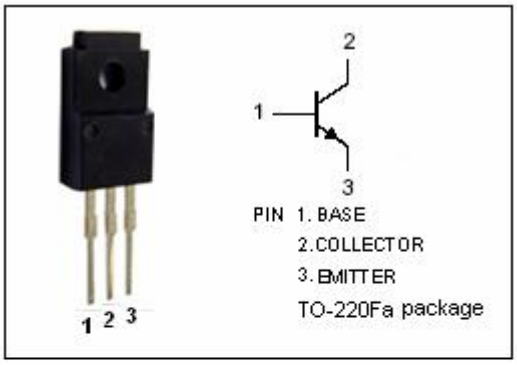
isc Silicon NPN Power Transistor — 2SD1594

DESCRIPTION

- Good Linearity of h_{FE}
- Collector-Emitter Breakdown Voltage
  : $V_{(BR)CEO}$= 100V(Min)
- Low Collector Saturation Voltage
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

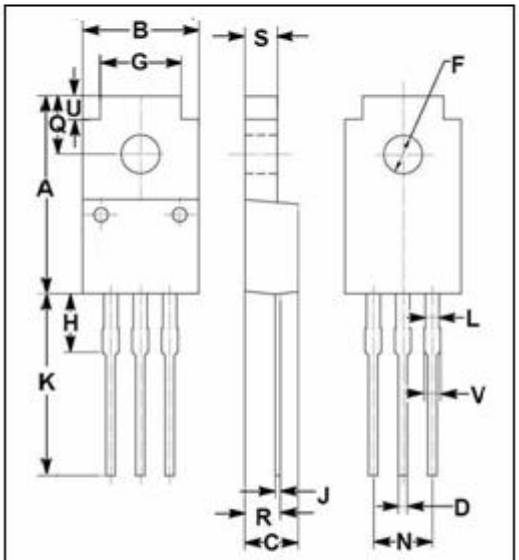


APPLICATIONS

- Designed for high speed switching industrial use.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V_{CBO}	Collector-Base Voltage	150	V
V_{CEO}	Collector-Emitter Voltage	100	V
V_{EBO}	Emitter-Base Voltage	7	V
I_C	Collector Current-Continuous	7	A
I_{CM}	Collector Current-Peak	15	A
I_B	Base Current-Continuous	3.5	A
P_C	Collector Power Dissipation @ T_a=25℃	1.5	W
	Collector Power Dissipation @ T_C=25℃	40	
T_J	Junction Temperature	150	℃
T_{stg}	Storage Temperature Range	-55~150	℃



DIM	mm MIN	mm MAX
A	16.85	17.15
B	9.54	10.10
C	4.35	4.65
D	0.75	0.90
F	3.20	3.40
G	6.90	7.20
H	5.15	5.45
J	0.45	0.75
K	13.35	13.65
L	1.10	1.30
N	4.98	5.18
Q	4.85	5.15
R	2.55	3.25
S	2.70	2.90
U	1.75	2.05
V	1.30	1.50

isc Silicon NPN Power Transistor 2SD1594

ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
$V_{CEO(SUS)}$	Collector-Emitter Sustaining Voltage	I_C= 50mA; I_{B1}= 0.5A, L= 1mH	100			V
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	I_C= 5A; I_B= 0.5A			0.6	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	I_C= 5A; I_B= 0.5A			1.5	V
I_{CBO}	Collector Cutoff Current	V_{CB}= 100V;I_E= 0			10	μA
I_{CER}	Collector Cutoff Current	V_{CE}= 100V;R_{BE}= 51Ω @T_C= 125℃			1	mA
I_{CEX}	Collector Cutoff Current	V_{CE}=100V;$V_{BE(off)}$= 1.5V V_{CE}=100V;$V_{BE(off)}$=1.5V@T_C= 125℃			10 1	μA mA
I_{EBO}	Emitter Cutoff Current	V_{EB}= 5V; I_C=0			10	μA
h_{FE-1}	DC Current Gain	I_C= 0.5A ; V_{CE}= 5V	40			
h_{FE-2}	DC Current Gain	I_C= 3A ; V_{CE}= 5V	40		240	
h_{FE-3}	DC Current Gain	I_C= 5A ; V_{CE}= 5V	20			
Switching Times						
t_{on}	Turn-on Time	I_C= 5A ,R_L= 10Ω , I_{B1}= I_{B2}= 0.5A,V_{CC}= 50V			0.5	μs
t_{stg}	Storage Time				0.5	μs
t_f	Fall Time				1.5	μs

◆ **h_{FE-2} Classifications**

R	O	Y
40-80	70-140	120-240

NOTICE：

ISC reserves the rights to make changes of the content herein the datasheet at any time without notification. The information contained herein is presented only as a guide for the applications of our products.

ISC products are intended for usage in general electronic equipment. The products are not designed for use in equipment which require specialized quality and/or reliability, or in equipment which could have applications in hazardous environments, aerospace industry, or medical field. Please contact us if you intend our products to be used in these special applications.

ISC makes no warranty or guarantee regarding the suitability of its products for any particular purpose, nor does ISC assume any liability arising from the application or use of any products, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.